








	<p>SI3493BDV-T1-E3</p>
	<p>Hersteller-Teilenummer: SI3493BDV-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 8A 6-TSOP</p> <p>Datenblätter:  SI3493BDV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 518500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3493BDV-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 8A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	518500 pcs Stock
detaillierte Beschreibung	P-Channel 20V 8A (Tc) 2.08W (Ta), 2.97W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	2.08W (Ta), 2.97W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Tc)
Rds On (Max) @ Id, Vgs	27.5 mOhm @ 7A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	43.5nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1805pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI3493BDV-T1-E3TR



















































SI3493BDV-T1-E3 ist neu im Original. Suche SI3493BDV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3493BDV-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3493BDV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3493BDV-T1-E3-S VISHAY SI3493BDV-T1-E3-S VISHAY</p>	 <p>SI3493BDV-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 8A 6-TSOP</p>	 <p>SI3483DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.7A 6-TSOP</p>	 <p>SI3483DV-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 4.7A 6-TSOP</p>
 <p>SI3493BDV-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 8A 6-TSOP</p>	 <p>SI3483DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.7A 6-TSOP</p>	 <p>SI3493BDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 8A 6-TSOP</p>	 <p>SI3484-A01-GM Energy Micro (Silicon Labs) PSE POWER MANAGEMENT IC</p>

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|--|---|--|---|--|
|  SI3473DV-T1-GE3 |  SI3474DV-T1-GE3 |  SI3474DV-T1-GE3 |  SI3475DV-T1-E3 |  SI3475DV-T1-E3 |
|  SI3475DV-T1-GE3 |  SI3475DV-T1-GE3 |  SI3476DV-T1-E3 |  SI3476DV-T1-GE3 |  SI3476DV-T1-GE3 |
|  SI3477DV-T1-E3 |  SI3477DV-T1-GE3 |  SI3477DV-T1-GE3 |  SI3481DV-T1-E3 |  SI3481DV-T1-E3 |
|  SI3481DV-T1-GE3 |  SI3481DV-T1-GE3 |  SI3483CDV-T1-E3 |  SI3483CDV-T1-E3 |  SI3483CDV-T1-GE3 |
|  SI3483CDV-T1-GE3 |  SI3483DV-T1-E3 |  SI3483DV-T1-E3 |  SI3483DV-T1-GE3 |  SI3483DV-T1-GE3 |
|  SI3493BDV-T1-E3 |  SI3493BDV-T1-E3-S |  SI3493BDV-T1-GE3 |  SI3493BDV-T1-GE3 |  SI3493DDV-T1-GE3 |
|  SI3493DDV-T1-GE3 |  SI3493DV |  SI3493DV-T1 |  SI3493DV-T1-E3 |  SI3493DV-T1-E3 |
|  SI3493DV-T1-E3 |  SI3493DV-T1-GE3 |  SI3493DV-T1-GE3 |  SI3495DV |  SI3495DV-T1-E3 |
|  SI3495DV-T1-E3 |  SI3495DV-T1-GE3 |  SI3495DV-T1-GE3 |  SI3499DV-T1-E3 |  SI3499DV-T1-E3 |
|  SI3499DV-T1-GE3 |  SI3499DV-T1-GE3 |  SI3500-A-GM |  SI3529DV-T1-GE3 |  SI3529DV-T1-GE3 |

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